INFORMATION DISCLOSURE CITATION IN AN APPLICATION  (PTO-1449)					ATTY. DOCKET NO. <b>50212-559</b>	Divi 09/9	SERIAL NO. Divisional of Appl. No. 09/995,854			
					APPLICANT Yoshiki NISHIBAYASHI, et al.					
					FILING DATE February 10, 2004	GROUP 1763				
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